

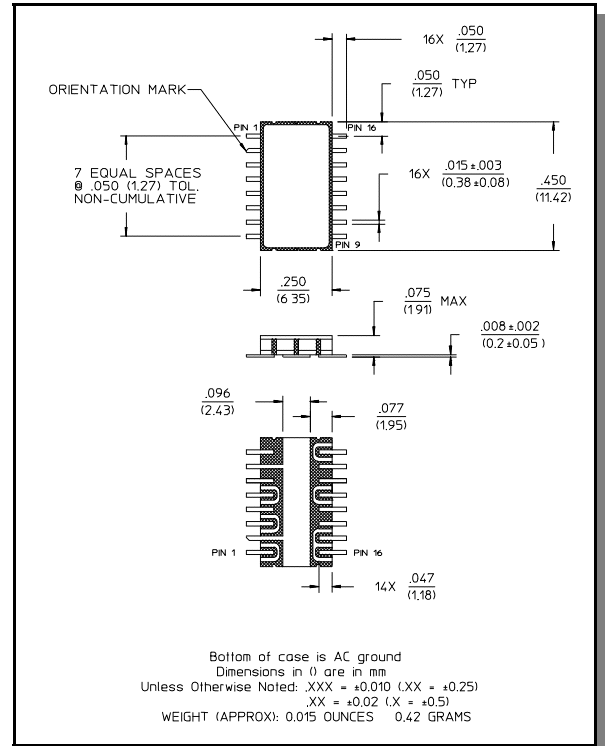
## Features

- Integral TTL Driver
- Low DC Power Consumption
- Surface Mount Package
- Low Cost/High Performance
- 50 Ohm Nominal Impedance

## Description

M/A-COM's SW10-0312 is a GaAs FET SPDT reflective switch with integral silicon ASIC driver. Packaged in a 16-lead ceramic surface mount package, this device offers excellent performance and repeatability from DC to 3 GHz while maintaining low power consumption. The SW10-0312 is ideally suited for use where fast speed, low power consumption and broadband applications are required.

## CR-9



## Electrical Specifications<sup>1,2</sup> T<sub>A</sub> = +25°C

Parameter	Test Conditions	Frequency	Units	Min	Typ	Max
Insertion Loss	—	DC - 3000 MHz	dB	—	0.9	1.2
		DC - 2000 MHz	dB	—	0.8	1.1
		DC - 1000 MHz	dB	—	0.7	0.9
		DC - 500 MHz	dB	—	0.6	0.8
VSWR	—	DC - 3000 MHz	Ratio	—	1.4:1	1.5:1
		DC - 2000 MHz	Ratio	—	1.3:1	1.4:1
		DC - 1000 MHz	Ratio	—	1.2:1	1.4:1
		DC - 500 MHz	Ratio	—	1.1:1	1.3:1
Isolation	—	DC - 3000 MHz	dB	27	36	—
		DC - 2000 MHz	dB	30	38	—
		DC - 1000 MHz	dB	35	42	—
		DC - 500 MHz	dB	40	45	—
Trise, Tfall	10% to 90%	—	ns	—	50	—
Ton, Toff	1.3V CTL to 90% / 10%	—	ns	—	150	—
Transients	In-Band	—	mV	—	50	—
1 dB Compression	Input Power	0.05 GHz	dBm	—	+25	—
		0.5 GHz to 3 GHz	dBm	—	+30	—
IP2	Two-Tone Input Power up to +5 dBm	0.05 GHz	dBm	—	+60	—
		0.5 GHz to 3 GHz	dBm	—	+65	—
IP3	Two-Tone Input Power up to +5 dBm	0.05 GHz	dBm	—	+40	—
		0.5 GHz to 3 GHz	dBm	—	+46	—
Vin Low	0V to 0.8V	—	µA	—	—	1
Vin High	2.0V to 5.0V	—	µA	—	—	1

1. All specifications apply when operated with bias voltages of +5V for V<sub>cc</sub> and -5V for V<sub>ee</sub>.  
 2. When DC blocks are used, a 10K ohm return to GND is required on the RFC port.

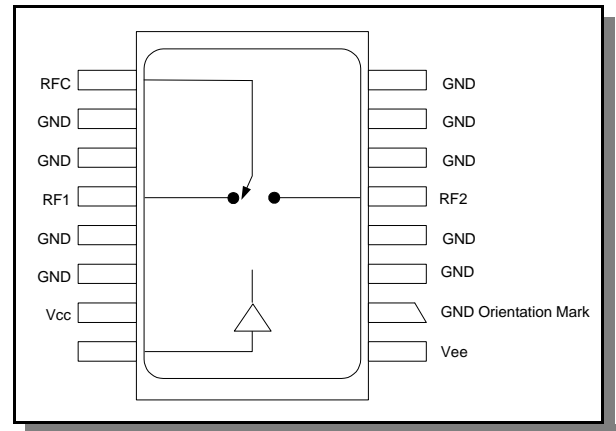
**Electrical Specifications: T<sub>A</sub> = +25°C**

Parameter	Test Conditions	Frequency	Units	Min	Typ	Max
V <sub>cc</sub>	+5.0V ± 10%	—	mA	—	—	1
V <sub>ee</sub>	-5.0V to -8.0V	—	mA	—	—	1

**Pin Configuration**

Pin No.	Function	Pin No.	Function
1	V <sub>ee</sub>	9	RFC
2	GND	10	GND
3	GND	11	GND
4	GND	12	RF1
5	RF2	13	GND
6	GND	14	GND
7	GND	15	V <sub>cc</sub>
8	GND	16	C1

**Pin Configuration (Top View)**



**Absolute Maximum Ratings <sup>3</sup>**

Parameter	Absolute Maximum
Max Input Power 50 MHz 500 - 2000 MHz	+27 dBm +34 dBm
Supply Voltages V <sub>cc</sub> V <sub>ee</sub>	+5.5V -8.5V
Control Voltage <sup>4</sup>	-0.5V, to V <sub>cc</sub> +0.5V
Operating Temperature	-40°C to +125°C
Storage Temperature	-65°C to +150°C

- 3. Operation of this device above any one of these parameters may cause permanent damage.
- 4. Standard CMOS TTL interface, latch-up will occur if logic signal is applied prior to power supply.

**Truth Table**

C1	Condition of Switch	
	RF Common to Each RF Port	
	RF1	RF2
LO	On	Off
HIGH	Off	On

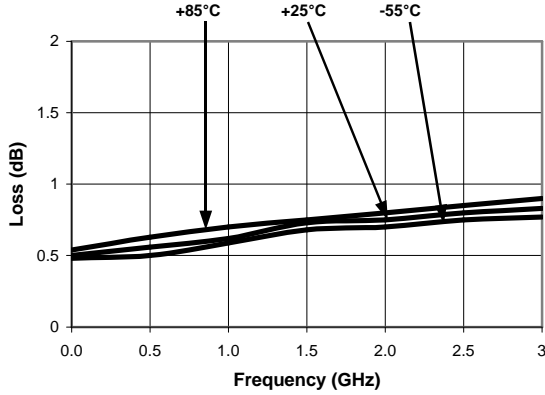
Specifications subject to change without notice.

- North America: Tel. (800) 366-2266
- Asia/Pacific: Tel.+81-44-844-8296, Fax +81-44-844-8298
- Europe: Tel. +44 (1344) 869 595, Fax+44 (1344) 300 020

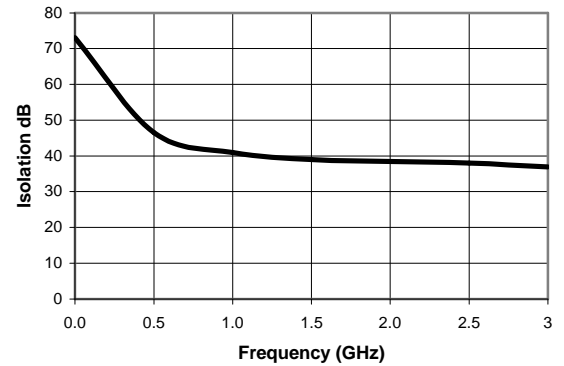
Visit [www.macom.com](http://www.macom.com) for additional data sheets and product information.

### Typical Performance Curves

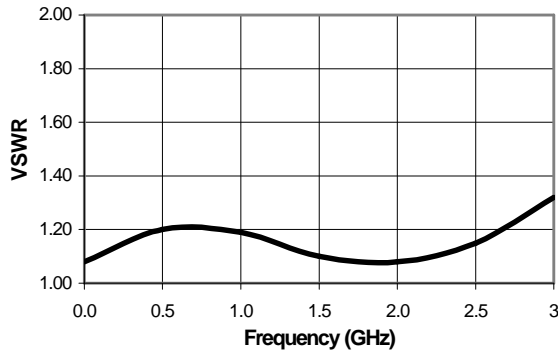
**Insertion Loss vs. Frequency**



**Isolation vs. Frequency**



**VSWR vs. Frequency**



### Ordering Information

Part Number	Package
SW10-0312	CR-9

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